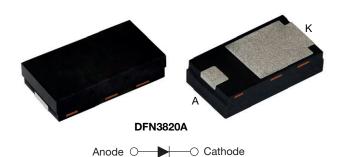
RoHS COMPLIANT

HALOGEN

FREE

Vishay Semiconductors

Ultrafast Rectifier, 1 A FRED Pt[®]



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	1 A				
V _R	200 V				
V _F at I _F	0.72 V				
t _{rr} (typ.)	15 ns				
I _{FSM}	32 A				
T _J max.	175 °C				
Package	DFN3820A				
Circuit configuration	Single				

FEATURES

- Very low profile typical height of 0.88 mm
- · Ideal for automated placement
- Wettable flanks allows easy inspection with AOI (automated optical inspection). No X-ray necessary
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency inverters, DC/DC converters, freewheeling diodes, clamping and snubber, polarity protection, and LED lighting

MECHANICAL DATA

Case: DFN3820A

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		200	V		
Average rectified forward current	I _{F(AV)}	T _M = 168 °C	1	٨		
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 10 ms sine pulse	32	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	200	-	-		
Forward voltage	V	I _F = 1 A	-	0.88	0.97	V	
Forward voltage	V _F	I _F = 1 A, T _J = 150 °C	-	0.72	0.76		
Deverse leekerse eurrent	I	V _R = V _R rated	-	-	1		
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	50	μΑ	
Junction capacitance	CT	V _R = 200 V	-	5	-	pF	

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_{\rm F} = 0.5 \text{ A}, I_{\rm R} = 1 \text{ A}$	A, I _{rr} = 0.25 A	-	15	23	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	9	-	ns
		T _J = 125 °C		-	13	-	
Peak recovery current		T _J = 25 °C	I _F = 1 A dI _F /dt = 500 A/μs V _R = 200 V	-	2.1	-	A
Fear recovery current	IRRM	T _J = 125 °C		-	3.1	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	11	-	nC
		T _J = 125 °C		-	22	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to mount	R _{thJM} ⁽¹⁾		-	6.5	8.5		
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	140	-	°C/W	
Weight			-	0.023	-	9	
Marking device		Case style DFN3820A		11	-12		

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC[®] 51-14 transient dual interface test method (TDIM)

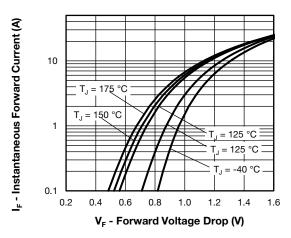


Fig. 1 - Typical Forward Voltage Drop Characteristics

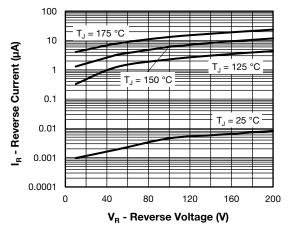


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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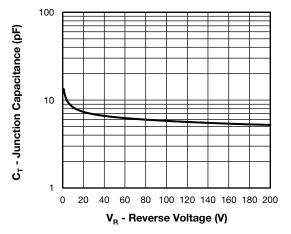


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

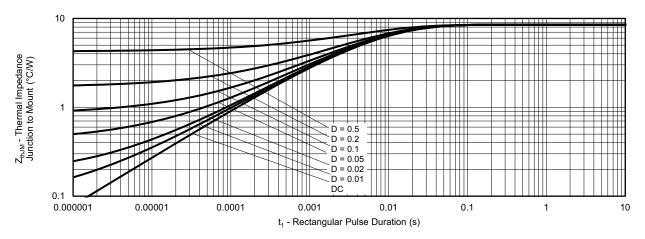
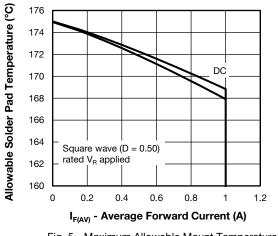
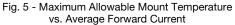
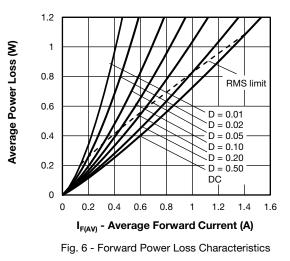


Fig. 4 - Maximum Transient Thermal Impedance, Junction to Mount







Note

 $\begin{array}{l} \mbox{Formula used: } T_M = T_J - (Pd + Pd_{REV}) \ x \ R_{thJM}; \\ \mbox{Pd} = \mbox{forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 5); \\ \mbox{Pd}_{REV} = \ inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ rated \ V_R \end{array}$

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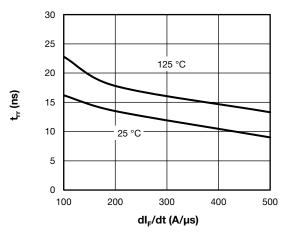
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Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

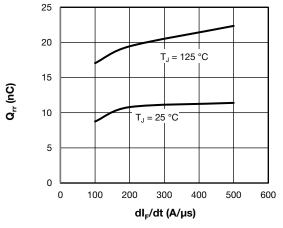


Fig. 8 - Typical Stored Charge vs. dl_F/dt

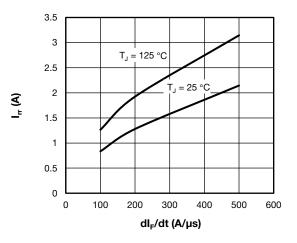


Fig. 9 - I_{rr} vs. dl/dt

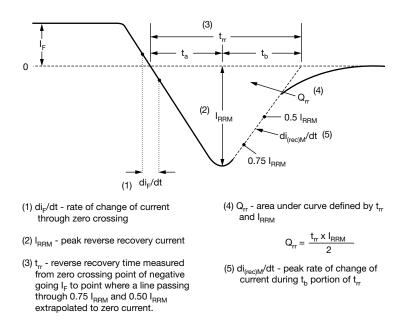


Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	vs-	1	Е	Α	н	02	-M3
	V 0-				••	02	
	1	2	3	4	5	6	7
	1	- Visl	nay Sen	niconduo	ctors pro	oduct	
	2	- Cur	rent rati	ng (1 =	1 A)		
	3	- Circ	cuit conf	iguratior	า:		
		E =	single o	liode			
	4	- A =	DFN38	20A pac	kage		
	5	- Pro	cess typ	e,			
		H =	ultrafas	t recove	ery		
	6	- Voli	age coo	le (02 =	200 V)		
	7	M3	s = halog	gen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-1EAH02-M3/H	н	3500	7" diameter plastic tape and reel				
VS-1EAH02-M3/I	I	14 000	13" diameter plastic tape and reel				

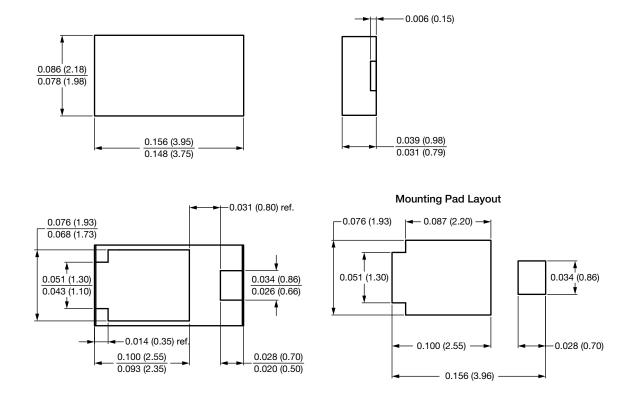
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?97066				
Part marking information	www.vishay.com/doc?97065				
Packaging information	www.vishay.com/doc?98488				
SPICE model	www.vishay.com/doc?97095				





DFN3820A, FRED Pt[®]

DIMENSIONS in inches (millimeters)





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